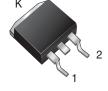
Vishay General Semiconductor

# **Dual Common Cathode Schottky Rectifier**

High Barrier Technology for Improved High Temperature Performance

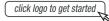
## D<sup>2</sup>PAK (TO-263AB)

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MBRB15H45CT

#### **DESIGN SUPPORT TOOLS**





## *W*

PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	2 x 7.5 A			
V <sub>RRM</sub>	45 V			
I <sub>FSM</sub>	150 A			
V <sub>F</sub>	0.55 V			
I <sub>R</sub>	50 µA			
T <sub>J</sub> max.	175 °C			
Package	D <sup>2</sup> PAK (TO-263AB)			
Circuit configuration	figuration Common cathode			

### FEATURES

- Power pack
- Guardring for overvoltage protection
- Low power loss, high efficiency
- Low forward voltage drop
- Low leakage current
- High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245  $^{\circ}\mathrm{C}$
- AEC-Q101 qualified available
  - Automotive ordering code: base P/NHE3\_A
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### **TYPICAL APPLICATIONS**

For use in low voltage, high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters, and polarity protection application.

#### **MECHANICAL DATA**

Case: D<sup>2</sup>PAK (TO-263AB)

Molding compound meets UL 94 V-0 flammability rating Base P/NHE3\_X - RoHS-compliant, AEC-Q101 qualified ("\_X" denotes revision code, e.g. A, B, ...)

**Terminals:** matte tin plated leads, solderable per J-STD-002 and JESD 22-B102 HE3 suffix meets JESD 201 class 2 whisker test

HE3 suffix meets JESD 201 class 2 whisker

Polarity: as marked

<b>MAXIMUM RATINGS</b> ( $T_C = 25 \ ^{\circ}C$ unless otherwise noted)						
PARAMETER			MBRB15H45CT	UNIT		
Maximum repetitive peak reverse voltage		V <sub>RRM</sub>	45			
Working peak reverse voltage		V <sub>RWM</sub>	45	V		
Maximum DC blocking voltage		V <sub>DC</sub>	45			
Maximum average forward rectified current (fig. 1)	total device	1	15	A		
	per diode	I <sub>F(AV)</sub>	7.5	A		
Non-repetitive avalanche energy at 25 °C, $I_{AS}$ = 4 A, L = 10 mH per diode			80	mJ		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I <sub>FSM</sub>	150	А		
Peak repetitive reverse surge current per diode at $t_{p}$ = 2.0 $\mu s,$ 1 kHz			1.0			
Peak non-repetitive reverse energy (8/20 µs waveform)			20	mJ		
Electrostatic discharge capacitor voltage Human body model: C = 100 F, R = 1.5 k $\Omega$			25	kV		
Voltage rate of change (rated V <sub>R</sub> )			10 000	V/µs		
Operating junction and storage temperature range		T <sub>J</sub> , T <sub>STG</sub>	-65 to +175	°C		

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1

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<b>ELECTRICAL CHARACTERISTICS</b> ( $T_C = 25$ °C unless otherwise noted)						
PARAMETER	SYMBOL	TEST CONDITIONS		MBRB15H45CT		UNIT
	STWIDOL			TYP.	MAX.	UNIT
Maximum instantaneous forward voltage per diode	V <sub>F</sub> <sup>(1)</sup>	I <sub>F</sub> = 7.5 A	T <sub>J</sub> = 25 °C	-	0.63	
		I <sub>F</sub> = 7.5 A	T <sub>J</sub> = 125 °C	0.50	0.55	V
		I <sub>F</sub> = 15 A	T <sub>J</sub> = 25 °C	-	0.75	
		I <sub>F</sub> = 15 A	T <sub>J</sub> = 125 °C	0.61	0.66	
Maximum reverse current per diode	I <sub>R</sub> <sup>(2)</sup>	$I_R^{(2)}$ Rated $V_R$	T <sub>J</sub> = 25 °C	-	50	μA
			T <sub>J</sub> = 125 °C	3.0	10	mA

Notes

<sup>(1)</sup> Pulse test: 300 µs pulse width, 1 % duty cycle

<sup>(2)</sup> Pulse test: pulse width  $\leq$  40 ms

<b>THERMAL CHARACTERISTICS</b> ( $T_C = 25$ °C unless otherwise noted)					
PARAMETER	SYMBOL	MBRB15H45CT	UNIT		
Maximum thermal resistance per diode	$R_{ ext{ heta}JC}$	3.0	°C/W		

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-263AB	MBRB15H45CTHE3_B/P (1)	1.35	Р	50/tube	Tube	
TO-263AB	MBRB15H45CTHE3_B/I <sup>(1)</sup>	1.35	I	800/reel	Tape and reel	

Note

<sup>(1)</sup> AEC-Q101 qualified

### RATINGS AND CHARACTERISTICS CURVES (T<sub>C</sub> = 25 °C unless otherwise noted)

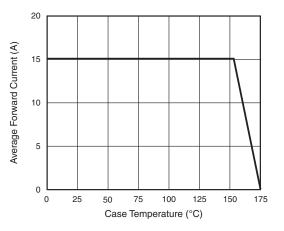


Fig. 1 - Forward Derating Curve Per Diode

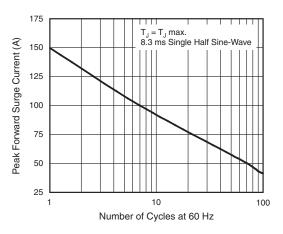
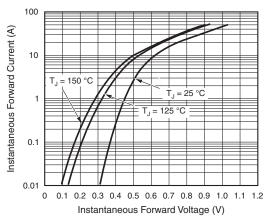


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

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Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

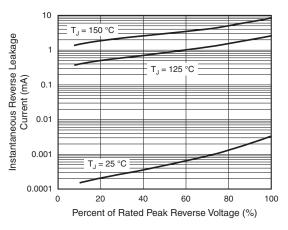


Fig. 4 - Typical Reverse Characteristics Per Diode

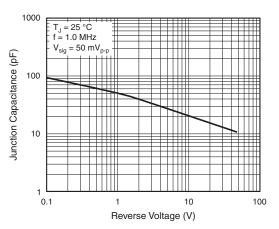


Fig. 5 - Typical Junction Capacitance Per Diode

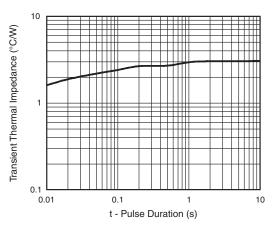
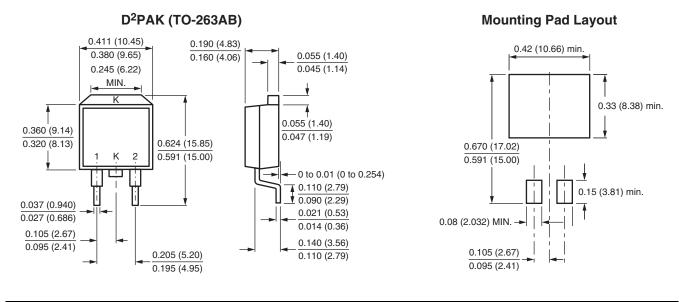


Fig. 6 - Typical Transient Thermal Impedance Per Diode

#### PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



Revision: 26-Sep-2018

3

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